



DMN3061SW

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
• •	60mΩ @ V _{GS} = 10V	2.7A
30V	100mΩ @ V _{GS} = 4.5V	2.1A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- General Purpose Interfacing Switch
- Power Management Functions
- DC-DC Converters
- Analog Switch

N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

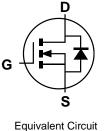
- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

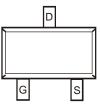
Mechanical Data

- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish—Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.027 grams (Approximate)



Top View





Top View

Ordering Information (Note 4)

Part Number	Case	Packaging
DMN3061SW-7	SOT323	3,000/Tape & Reel
DMN3061SW-13	SOT323	10,000/Tape & Reel

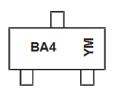
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.</p>

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



BA4 = Product Type Marking Code YM or \overline{Y} M= Date Code Marking Y or \overline{Y} = Year (ex: H = 2020) M = Month (ex: 9 = September)

Date Code Key

Notes:

•												
Year	2019	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	G	Н	-	J	K	L	М	Ν	0	Р	R	S
	1				1							
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	Vdss	30	V		
Gate-Source Voltage	V _{GSS}	±20	V		
Continuous Drain Current (Note 6) V _{GS} = 10V	ID	2.7 2.2	A		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	lдм	22	А		
Maximum Body Diode Forward Current (Note 5)			ls	0.67	А

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	0.49	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Roja	254	°C/W
Total Power Dissipation (Note 6)		PD	0.65	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	191	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

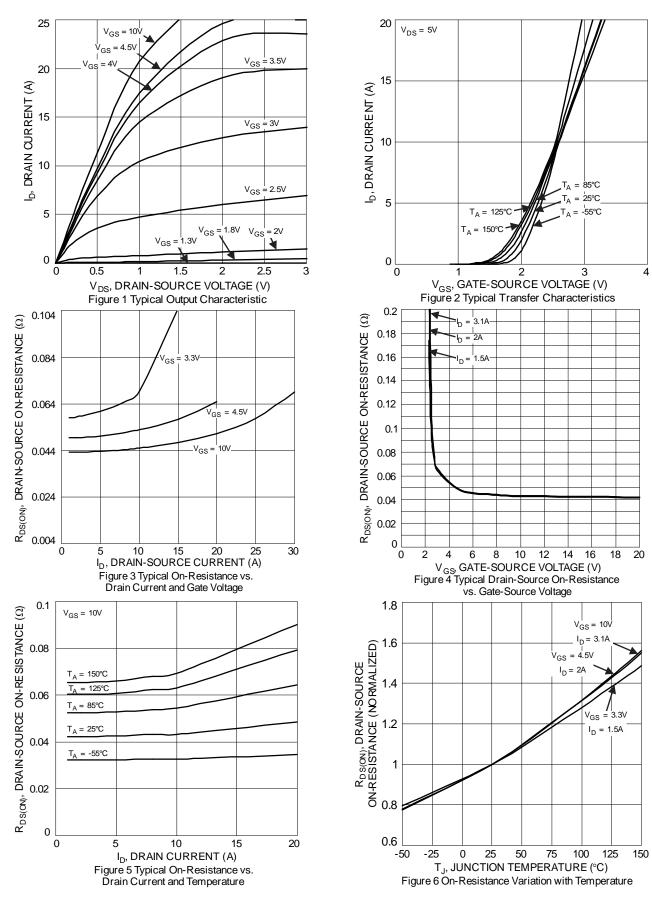
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						·
Drain-Source Breakdown Voltage	BV _{DSS}	30		—	V	$V_{GS} = 0V, I_D = 250 \mu A$
Zero Gate Voltage Drain Current @Tc = +25°C	IDSS	_	_	1.0	μA	$V_{DS} = 24V, V_{GS} = 0V$
Gate-Source Leakage	Igss	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(TH)}	0.5	_	1.8	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
			41	60		VGS = 10V, ID = 3.1A
Static Drain-Source On-Resistance	RDS(ON)		48	100	mΩ	VGS = 4.5V, ID = 2A
			56	200		V _{GS} = 3.3V, I _D = 1.5A
Diode Forward Voltage	Vsd		0.7	1	V	$V_{GS} = 0V$, $I_{S} = 1A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		278	—	рF	
Output Capacitance	Coss		44	—	pF	− V _{DS} = 15V, V _{GS} = 0V, − f = 1.0MHz
Reverse Transfer Capacitance	Crss		29	—	pF	
Gate Resistance	Rg		4.2	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge	Qg	_	3.5		nC	
Gate-Source Charge	Qgs	_	0.1	_	nC	V _{DS} = 15V, V _{GS} = 4.5V, I _D = 3A
Gate-Drain Charge	Qgd	_	1.3	_	nC	
Turn-On Delay Time	tD(ON)		5.7	_	ns	
Turn-On Rise Time			97	_	ns	$V_{GS} = 10V, V_{DS} = 15V,$
Turn-Off Delay Time			12.6	_	ns	$R_G = 3\Omega, R_L = 1.7\Omega$
Turn-Off Fall Time	tF	_	51	—	ns	

Notes:

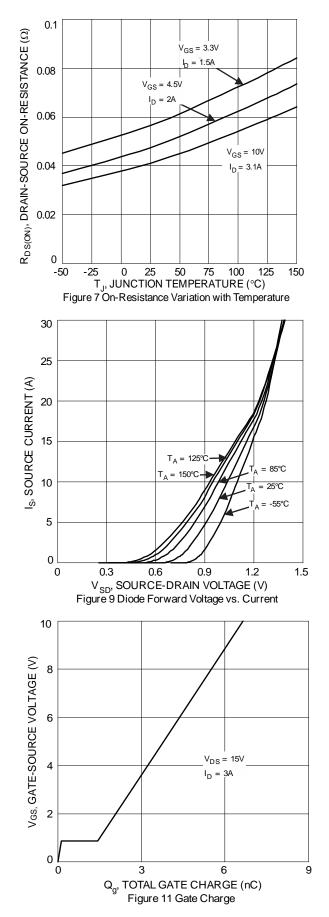
Device mounted on FR-4 substrate PC board, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.

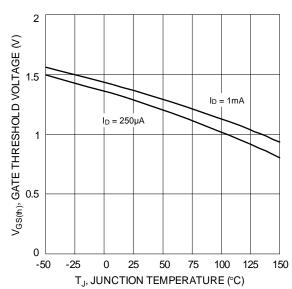


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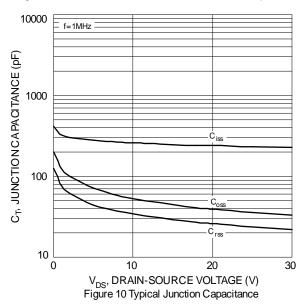


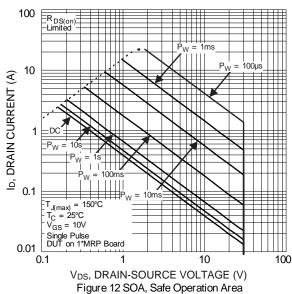




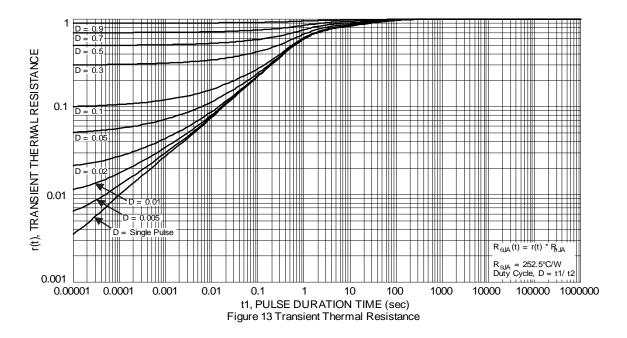








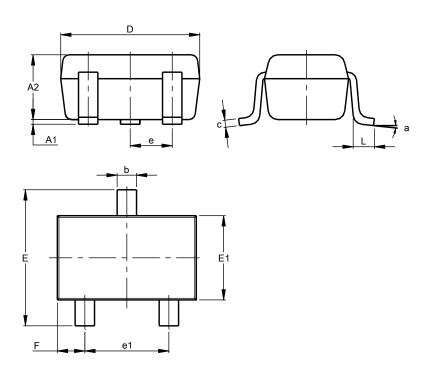






Package Outline Dimensions

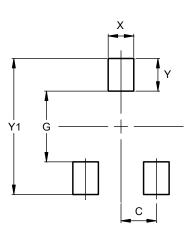
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT323									
Dim	Min	Max	Тур						
A1	0.00	0.10	0.05						
A2	0.90	1.00	0.95						
b	0.25	0.40	0.30						
С	0.10	0.18	0.11						
D	1.80	2.20	2.15						
Е	2.00	2.20	2.10						
E1	1.15	1.35	1.30						
е	C).650 B	SC						
e1	1.20	1.40	1.30						
F	0.375	0.475	0.425						
L	0.25	0.40	0.30						
а	0°	8°							
All	All Dimensions in mm								

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT323

SOT323

Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.470
Y	0.600
Y1	2.500



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